

P-Channel Power MOSFET

-20V, -4.7A, 50mΩ

FEATURES

- Halogen-free
- Suited for 1.8V drive applications
- Low profile package

APPLICATION

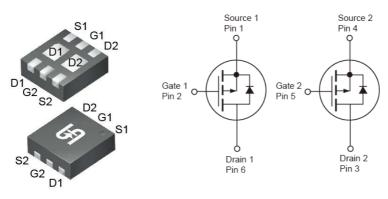
- Battery Pack
- Load Switch

KEY PERFORMANCE PARAMETERS				
PARAMETER		VALUE	UNIT	
V_{DS}		-20	V	
	V _{GS} =- 4.5V	50		
R _{DS(on)} (max)	V _{GS} = -2.5V	65	mΩ	
	V _{GS} = -1.8V	85		
Q_{g}		9.6	nC	





TDFN2x2



Notes: Moisture sensitivity level: level 3. Per J-STD-020

ABSOLUTE MAXIMUM RATINGS (T _A = 25°C unless otherwise noted)				
PARAMETER		SYMBOL	LIMIT	UNIT
Drain-Source Voltage		V_{DS}	-20	V
Gate-Source Voltage		V_{GS}	±10	V
Continuous Drain Current (Note 1)	$T_C = 25$ °C	ı	-4.7	^
	$T_C = 100$ °C	l _D	-2.82	A
Pulsed Drain Current (Note 2)		I _{DM}	-18.8	А
Total Power Dissipation @ T _C = 25°C		P _{DTOT}	0.62	W
Operating Junction and Storage Temper	erature Range	T _J , T _{STG}	- 55 to +150	°C

THERMAL PERFORMANCE				
PARAMETER	SYMBOL	LIMIT	UNIT	
Junction to Ambient Thermal Resistance	$R_{\Theta JA}$	200	°C/W	

Notes: $R_{\theta JA}$ is the sum of the junction-to-case and case-to-ambient thermal resistances. $R_{\theta JA}$ is guaranteed by design while $R_{\theta CA}$ is determined by the user's board design. $R_{\theta JA}$ shown below for single device operation on FR-4 PCB in still air.



PARAMETER	CONDITIONS	SYMBOL	MIN	TYP	MAX	UNIT
Static (Note 3)		1		l		l .
Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_D = -250\mu A$	BV _{DSS}	-20			V
Gate Threshold Voltage	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$	$V_{GS(TH)}$	-0.3	-0.6	-0.8	V
Gate Body Leakage	$V_{GS} = \pm 10V, V_{DS} = 0V$	I _{GSS}			±100	nA
Zero Gate Voltage Drain Current	$V_{DS} = -20V, V_{GS} = 0V$	I _{DSS}			-1	μA
	$V_{GS} = -4.5V, I_{D} = -3A$			42	50	mΩ
Drain-Source On-State Resistance	$V_{GS} = -2.5V, I_D = -2A$	R _{DS(ON)}		57	65	
	V _{GS} = -1.8V, I _D = -1A			75	85	
Forward Transconductance	$V_{DS} = -10V, I_{D} = -3A$	g _{fs}		7		S
Dynamic (Note 4)						
Total Gate Charge		Q_g		9.6	13	
Gate-Source Charge	$V_{DS} = -10V, I_{D} = -3.0A,$	Q_{gs}		1.6	2	nC
Gate-Drain Charge	$V_{GS} = -4.5V$	Q_{gd}		2	4	
Input Capacitance	$V_{DS} = -10V, V_{GS} = 0V,$ - f = 1.0MHz	C _{iss}		850	1230	
Output Capacitance		C _{oss}		70	100	pF
Reverse Transfer Capacitance		C _{rss}		55	80	
Switching (Note 5)						•
Turn-On Delay Time		t _{d(on)}		6	11	
Turn-On Rise Time	$V_{DD} = -10V$,	t _r		21.6	41	
Turn-Off Delay Time	$R_{GEN} = 25\Omega,$ $I_{D} = -1A, V_{GS} = -4.5V,$	t _{d(off)}		51	97	ns
Turn-Off Fall Time		t _f		13.8	26	
Source-Drain Diode (Note 3)		•				
Continuous Source Current	$V_G = V_D = 0V$	Is			-4.7	Α
Pulsed Source Current	Force Current	I _{SM}			-18.8	Α
Forward On Voltage	$I_S = -1.0A, V_{GS} = 0V$	V_{SD}			-1.0	V

Notes:

- 1. Current limited by package
- 2. Pulse width limited by the maximum junction temperature
- 3. Pulse test: PW ≤ 300µs, duty cycle ≤ 2%
- 4. For DESIGN AID ONLY, not subject to production testing.
- 5. Switching time is essentially independent of operating temperature.



Taiwan Semiconductor

ORDERING INFORMATION

PART NO.	PACKAGE	PACKING
TSM500P02DCQ RFG	TDFN 2x2	3,000pcs / 7" Reel

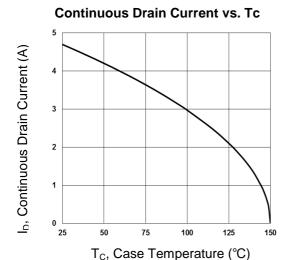
Note:

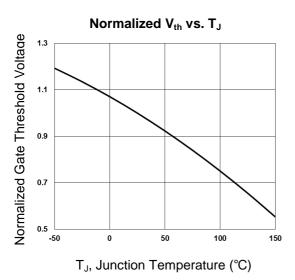
- 1. Compliant to RoHS Directive 2011/65/EU and in accordance to WEEE 2002/96/EC
- 2. Halogen-free according to IEC 61249-2-21 definition

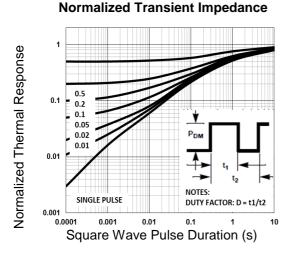


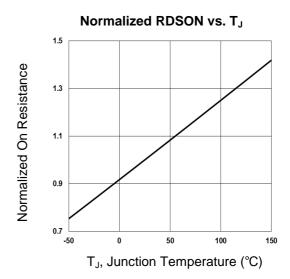
CHARACTERISTICS CURVES

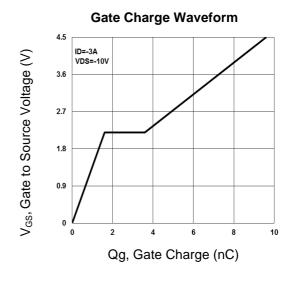
 $(T_C = 25^{\circ}C \text{ unless otherwise noted})$

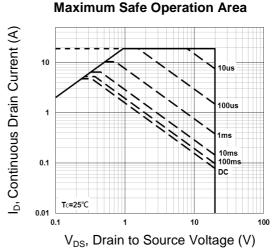










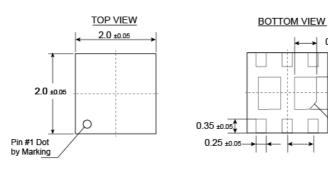


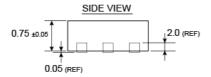
0.55 ±0.05



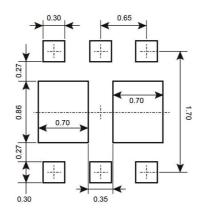
PACKAGE OUTLINE DIMENSIONS (Unit: Millimeters)

TDFN2x2

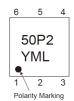




SUGGESTED PAD LAYOUT (Unit: Millimeters)



MARKING DIAGRAM



Y = Year Code

M = Month Code for Halogen Free Product

O =Jan P =Feb Q =Mar R =Apr

S = May T = Jun U = Jul V = Aug

W =Sep X =Oct Y =Nov Z =Dec

 $L = \text{Lot Code } (1\sim 9, A\sim Z)$



Taiwan Semiconductor

Notice

Specifications of the products displayed herein are subject to change without notice. TSC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No license, express or implied, to any intellectual property rights is granted by this document. Except as provided in TSC's terms and conditions of sale for such products, TSC assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale and/or use of TSC products including liability or warranties relating to fitness for a particular purpose, merchantability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications. Customers using or selling these products for use in such applications do so at their own risk and agree to fully indemnify TSC for any damages resulting from such improper use or sale.

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Taiwan Semiconductor:

TSM500P02DCQ RFG